## Exciton Dynamics in Heterojunction Thin-film Devices Based on Exciplex-Sensitized Triplet-Triplet Annihilation

## Supporting information

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**Figure S1.** (a) Early time (0.0-0.8 ns) TrPL decays of monolayer ADN, and bilayers m-MTDATA/ADN, and DMPPP/ADN. (b) trilayer m-MTDATA/DMPPP/ADN with different DMPPP thickness (0, 5, 10, 15 nm), and single layer ADN thin films. TrPL decays were taken at a single wavelength (440 nm) that reflects the ADN. The same trends are seen as in Figure 4 of the manuscript.



Figure S2. (a) Late time (0.0-0.8  $\mu$ s) TrPL decays of monolayer ADN, and bilayers m-MTDATA/ADN, and DMPPP/ADN. (b) trilayer m-MTDATA/DMPPP/ADN with different DMPPP thickness (0, 5, 10, 15 nm), and single layer ADN thin films. TrPL decays were integrated from 400-600 nm.



Figure S3. Intensity dependence of long time PL spectra, showing enhanced ADN PL at high intensities due to TTA



**Figure S4**. (a) Late time (0 - 0.8 us) TrPL decays of monolayer ADN, and bilayer DMPPP/ADN. (b) Corresponding PL spectra integrated from 0 - 0.8 us.



**Figure S5.** TrPL of ADN prompt fluorescence decays of m-MTDATA/ADN bilayer (a) and m-MTDATA/ADN/DMPPP trilayer of various DMPPP thickness (b-d) fit to equation 2.



**Figure S6.** TrPL decays in the 0-0.8 ns window of monolayer DPAVBi and DPAVBi doped into ADN with 10% in volume ratio.